AURA-WAVE

Ref. CPSKFDN40ECR2DP

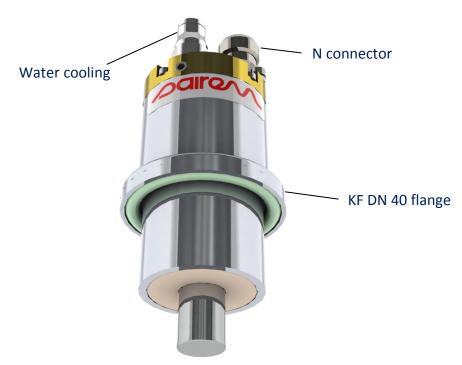


AURA-WAVE is an **E**lectron **C**yclotron **R**esonance (ECR) coaxial plasma source [1]. It has been designed to be self-adapted once the plasma ignited. A magnetic field combined to the electromagnetic wave allows the creation of plasma at low pressure due to **E**lectron **C**yclotron **R**esonance.

The **AURA-WAVE** ECR microwave plasma source has been designed to sustain microwave plasma over several decades of pressure, i.e. from 10^{-4} mbar to a few 10^{-2} mbar and from a few watt microwave power whatever the gas. Equally, the coaxial plasma source was designed to avoid inside power-losses and has proved to be matched [2-5], i.e. no reflected power with no additional impedance matching system over 2 to 3 pressure decades, depending on the plasma gas. Plasma density up to a **few 10**¹¹ **cm**⁻³ [6] could be easily obtained in multisource configuration in different gases like argon, oxygen, nitrogen.

When combined with SAIREM solid state microwave generator, it possible to control the power transmitted to the plasma with one watt increment; low mismatching that may appear in the operating conditions can be balanced due to the variable frequency of the solid state generator and thus permits to extend the operating condition range of the **AURA-WAVE**.

AURA-WAVE is designed to be used equally in R&D laboratories and industry for a very large range of applications. Typical applications of such source are generation of radicals (e.g. atomic oxygen), etching, PECVD, surface treatment (nitruration, cleaning etc.) and it is ideal for working in the low pressure range i.e. with high energy particles.



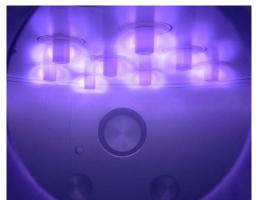
AURA-WAVE ECR coaxial plasma source

Technical specification

| REF | CPSKFDN40ECR2DP |
|--|---|
| Frequency | 2400 – 2500 MHz, 0.1 MHz increment |
| Microwave power | Max. 200 W |
| Working pressure range | A few 10 ⁻⁴ mbar to a few 10 ⁻² mbar |
| Plasma density (measured in Ar-O ₂ -N ₂) | One source: $2-5 \times 10^{10}$ cm ⁻³ at 160 mm $\sim 10^{11}$ cm ⁻³ at 100 mm Multisource: 10^{11} cm ⁻³ at 160 mm a few 10^{11} cm ⁻³ at 100 mm |
| Connections | Standard KF DN40 flange |
| Cooling by water | Push-fit connectors for OD 6 mm tubing. Water-cooling of the sources is mandatory (at least 0.5 l/min). The warranty will be void in case of operation without water-cooling. |

OBSERVATIONS

Multi-sources can be used for scaling-up in crown distribution for volume plasma processing or in matrix distribution for planar plasma processing. As each *AURA-WAVE* has its own microwave generator, it is possible to control exactly the transmitted power to each plasma source whatever the number. For example, in matrix distribution, the losses in uniformity due to edge effect of the peripheral plasma sources can be compensated by increasing their microwave power and thus increase the surface of uniform treatment area.







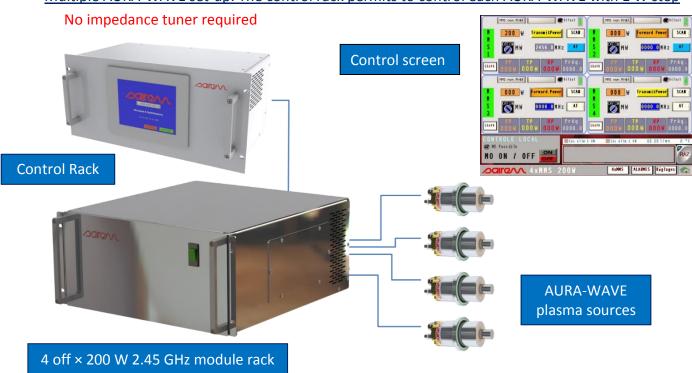
Example of integration of 8 **AURA-WAVE** sources on the top lid of a plasma reactor – Argon plasma at 10^{-2} mbar, 20 W / source – N_2 -Ar plasma at 10^{-2} mbar, 100 W / source. In this example it is possible to integrate up to 16 **AURA-WAVE** for 300 mm processing.

SET-UP of AURA-WAVE and solid state microwave generator

The functionality of the plasma source is possible if the source is connected to a 2.45 GHz solid state microwave generator. In case of multiple plasma sources, solid state modules can be integrated; the control can be done via CANopen® or via a control rack with a touch screen.



Multiple AURA-WAVE set-up. The control rack permits to control each AURA-WAVE with 1 W step



REFERENCES

- [1] S Béchu, A Bès, A Lacoste, J Pelletier, Device and method for producing and/or confining a plasma, Patent WO 2010/049456.
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- [3] L Latrasse, M Radoiu, J-M Jacomino, A Grandemenge, Facility for microwave treatment of a load, Patent WO 2012/146870.
- [4] L Latrasse, M Radoiu, Elementary device for applying a microwave energy with coaxial applicator, Patent WO 2017/060611.
- [5] L Latrasse, M Radoiu, T Nelis, O Antonin, Self-matching plasma sources using 2.45 GHz solid-state generators: microwave design and operating performance, J Microw Power Electromagn Energy. 2017, DOI: 10.1080/08327823.2017.1388338.
- [6] L Latrasse, M Radoiu, J Lo, P Guillot, 2.45-GHz microwave plasma sources using solid state microwave generators. ECR-type plasma source. J Microw Power Electromagn Energy. 2017, 50:308–321.

